# onsemi

### **<u>MOSFET</u> – Power,** Dual, N-Channel, for 3-Cells Lithium-ion Battery Protection, WLCSP8

**30 V, 2.6 mΩ, 30 A** 

## EFC4C002NL

This N-Channel Power MOSFET is produced using onsemi trench technology, which is specifically designed to minimize gate charge and ultra low on resistance.

This device is suitable for applications of Drone or Notebook PC.

#### Features

- Ultra Low On-Resistance
- Low Gate Charge
- Common-Drain Type
- These Device is Pb-Free, Halogen Free and is RoHS Compliant

#### Applications

• 3-Cells Lithium-ion Battery Charging and Discharging Switch

#### SPECIFICATIONS

#### **ABSOLUTE MAXIMUM RATINGS** at $T_A = 25^{\circ}C$ (Note 1)

Parameter	Symbol	Value	Unit
Source to Source Voltage	V <sub>SSS</sub>	30	V
Gate to Source Voltage	V <sub>GSS</sub>	±20	V
Source Current (DC)	۱ <sub>S</sub>	30	А
Source Current (Pulse) PW ≤ 10 μs, Duty Cycle ≤ 1%	I <sub>SP</sub>	120	A
Total Dissipation (Note 1)	PT	2.6	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55 to +150	°C

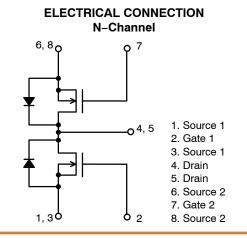
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient (Note 1)	$R_{\theta JA}$	48	°C/W

1. Surface mounted on ceramic substrate (5000 mm<sup>2</sup>  $\times$  0.8 mm).

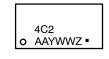
V <sub>SSS</sub>	R <sub>SS(on)</sub> Max	I <sub>S</sub> Max
	$2.6~\mathrm{m}\Omega$ @ 10 V	
30 V	3.3 mΩ @ 8 V	30 A
	5.1 mΩ @ 4.5 V	





WLCSP8 CASE 567MC

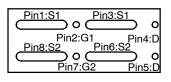
#### MARKING DIAGRAM



4C2 = Specific Device Code

- AA = Assembly Location
- Y = Year
- WW = Work Week
- Z = Lot Traceability
- = Pb-Free Package

#### **PIN ASSIGNMENT**



#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 6 of this data sheet.

#### **ELECTRICAL CHARACTERISTICS** at $T_A$ = 25 $^{\circ}C$

				Value		
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Source to Source Breakdown Voltage	V(BR)SSS	$I_S = 1 \text{ mA}, V_{GS} = 0 \text{ V}$ Test Circuit 1	30			V
Zero-Gate Voltage Source Current	I <sub>SSS</sub>	$V_{SS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$ Test Circuit 1			1	μA
Gate to Source Leakage Current	I <sub>GSS</sub>	$V_{GS}$ = 20 V, $V_{SS}$ = 0 V Test Circuit 2			200	nA
Gate Threshold Voltage	V <sub>GS</sub> (th)	$V_{SS} = 10 \text{ V}, \text{ I}_{S} = 1 \text{ mA}$ Test Circuit 3	1.3		2.2	V
Forward Transconductance	9 <sub>FS</sub>	$V_{SS} = 10 \text{ V}, \text{ I}_{S} = 10 \text{ A}$ Test Circuit 4		16		S
Static Source to Source On-State Resistance	R <sub>SS</sub> (on)	$V_{GS} = 10 \text{ V}, \text{ I}_{S} = 10 \text{ A}$ Test Circuit 5	1.5	2.0	2.6	mΩ
		$V_{GS}$ = 8 V, I <sub>S</sub> = 10 A Test Circuit 5	1.6	2.1	3.3	mΩ
		$V_{GS}$ = 4.5 V, I <sub>S</sub> = 10 A Test Circuit 5	2.2	2.9	5.1	mΩ
Static Drain to Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>S</sub> = 1 A		10		mΩ
Gate Resistance	R <sub>G</sub>			3		Ω
Turn-ON Delay Time	t <sub>d</sub> (on)	V <sub>SS</sub> = 15 V, V <sub>GS</sub> = 10 V		40		ns
Rise Time	t <sub>r</sub>	I <sub>S</sub> = 10 A Test Circuit 6		750		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	1		280		ns
Fall Time	t <sub>f</sub>	1		105		ns
Input Capacitance	Ciss	V <sub>SS</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1 MHz		6.200		pF
Total Gate Charge	Qg	$V_{SS}$ = 15 V, $V_{GS}$ = 4.5 V, $I_S$ = 15 A Test Circuit 7	1	45		nC
Forward Source to Source Voltage	V <sub>F(S-S)</sub>	$I_S = 10 \text{ A}, V_{GS} = 0 \text{ V}$ Test Circuit 8		0.75	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

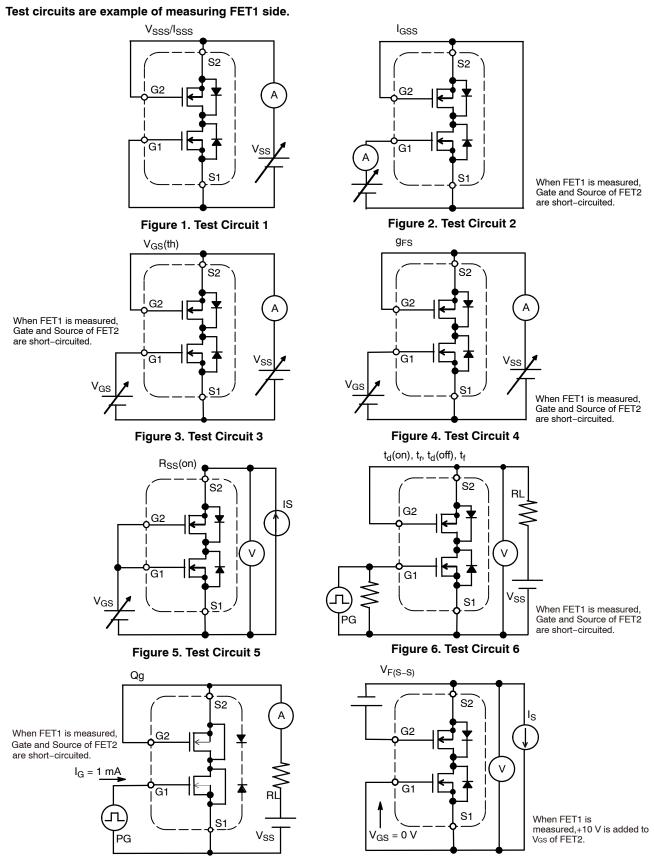
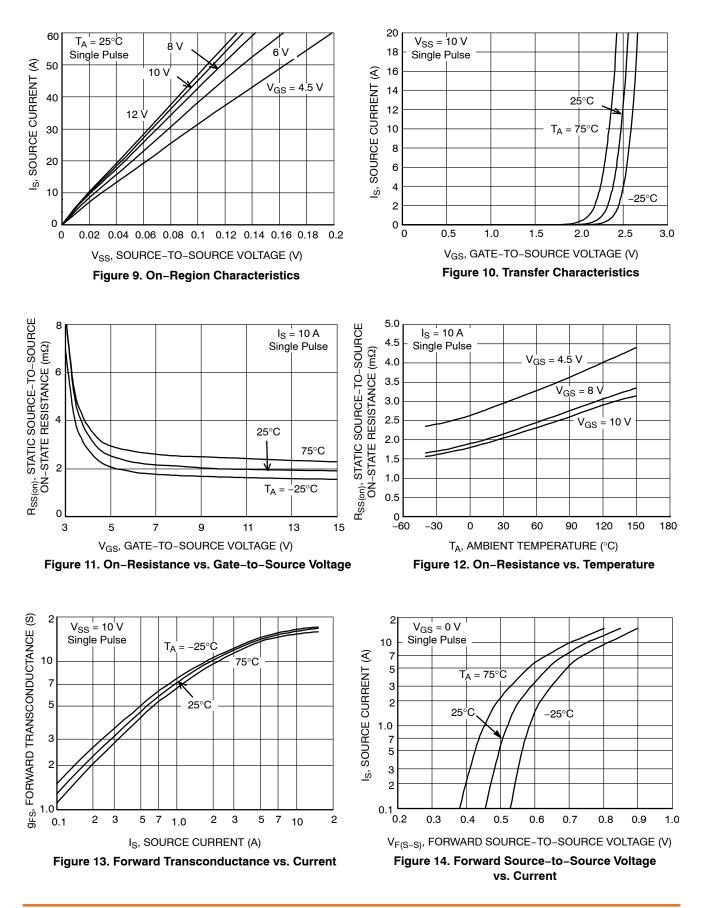


Figure 7. Test Circuit 7

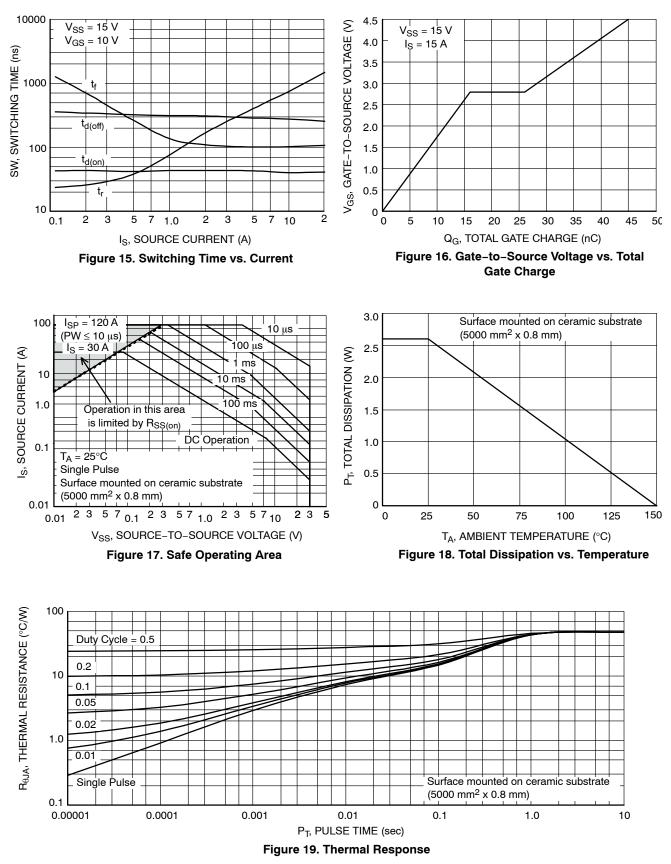
Figure 8. Test Circuit 8

NOTES: When FET2 is measured, the position of FET1 and FET2 is switched.

#### **TYPICAL CHARACTERISTICS**



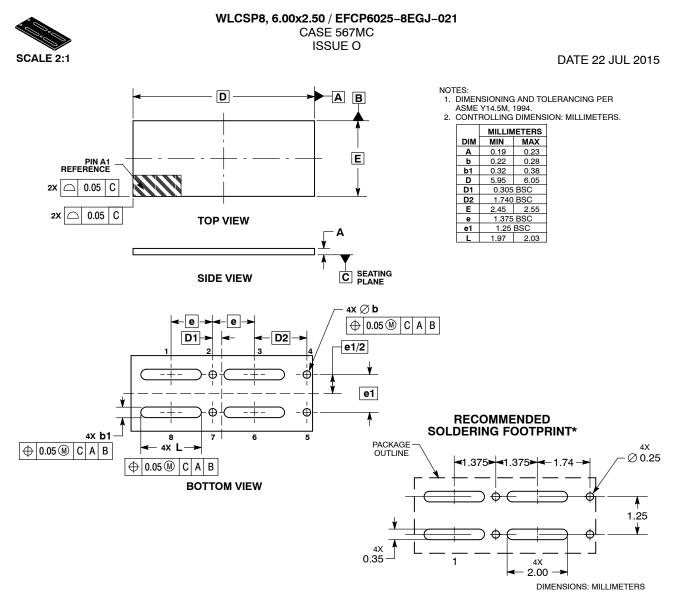




#### **ORDERING INFORMATION**

Device	Marking	Package	Shipping (Qty / Packing) $^{\dagger}$
EFC4C002NLTDG	4C2	WLCSP8 6.00x2.50 (Pb-Free / Halogen Free)	5000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	WLCSP8, 6.00X2.50 / EFCP6025-8EGJ-021 PAGE 1 OF 1			
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**MECHANICAL CASE OUTLINE** 

PACKAGE DIMENSIONS

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